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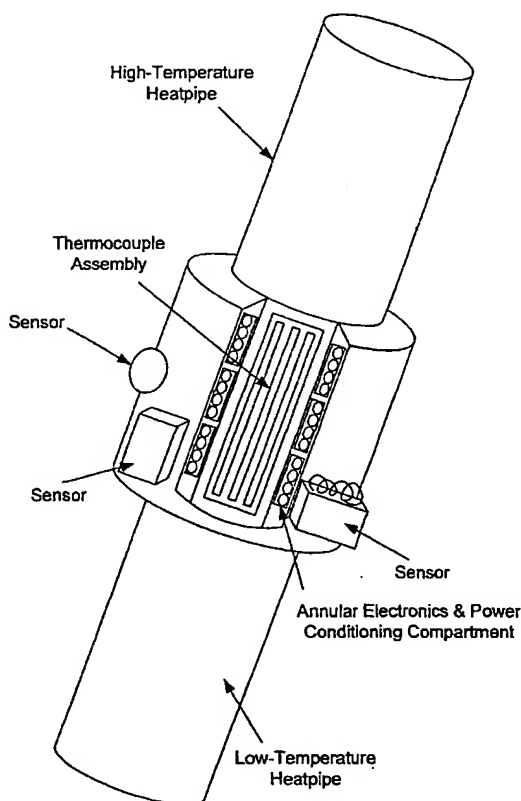
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(54) Title: THERMOELECTRIC DEVICES AND APPLICATIONS FOR THE SAME



(57) Abstract: High performance thin film thermoelectric  
couples and methods of making the same are disclosed. Such  
couples allow fabrication of at least microwatt to watt-level  
power supply devices operating at voltages greater than  
one volt even when activated by only small temperature  
differences.

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